

用途:用于开关、反相电路、界面电路以及驱动电路中。

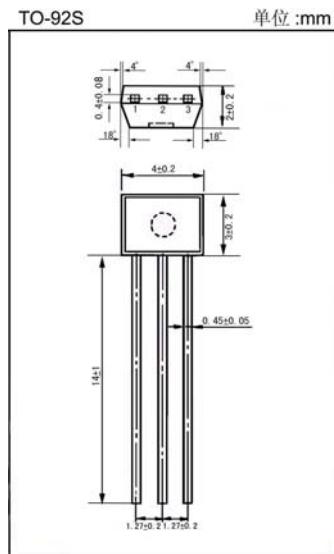
Purpose: Switching, inverter circuit, interface circuit and driver circuit applications.

特点:内装偏置电阻, 简化线路设计, 减少元件和制造流程。

Features: With built-in bias resistors, simplify circuit design, reduce a quantity of parts and manufacturing process.

极限参数/Absolute maximum ratings (Ta=25°C)

参数符号 Symbol	数值 Rating	单位 Unit
V <sub>CBO</sub>	-50	V
V <sub>CEO</sub>	-50	V
V <sub>EBO</sub>	-10	V
I <sub>C</sub>	-100	mA
P <sub>C</sub>	400	mW
T <sub>j</sub>	150	°C
T <sub>stg</sub>	-55~150	°C



电性能参数/Electrical characteristics (Ta=25°C)

参数符号 Symbol	测试条件 Test condition	数值 Rating			单位 Unit
		最小值 Min	典型值 Typ	最大值 Max	
V <sub>I(ON)</sub>	V <sub>CE</sub> =-0.2V I <sub>c</sub> =-5.0mA	-1.2		-2.4	V
V <sub>I(OFF)</sub>	V <sub>CE</sub> =-5.0V I <sub>c</sub> =-0.1mA	-1.0		-1.5	V
I <sub>CBO</sub>	V <sub>CB</sub> =-50V I <sub>E</sub> =0			-0.1	μA
I <sub>CEO</sub>	V <sub>CE</sub> =-50V I <sub>B</sub> =0			-0.5	μA
I <sub>EBO</sub>	V <sub>EB</sub> =-10V I <sub>c</sub> =0	-380		-710	μA
h <sub>FE</sub>	V <sub>CE</sub> =-5.0V I <sub>c</sub> =-10mA	50			
V <sub>CE(sat)</sub>	I <sub>c</sub> =-5.0mA I <sub>B</sub> =-0.25mA		-0.1	-0.3	V
f <sub>T</sub>	V <sub>CE</sub> =-10V I <sub>c</sub> =-5.0mA		200		MHz
C <sub>ob</sub>	V <sub>CB</sub> =-10V I <sub>E</sub> =0mA f=1.0MHz		3.0	6.0	pF
R <sub>i</sub>		7	10	13	KΩ
R <sub>i</sub> /R <sub>2</sub>		0.9	1.0	1.1	

等效电路图

